

Mechanical loss of crystalline and amorphous coatings

I. Martin¹, K. Craig¹, P. Murray¹, R. Robie¹, S. Reid², A. Cumming¹,
R. Bassiri³, M. M. Fejer³, J. Harris³, M. Hart¹, G. Harry⁴,
K. Haughian¹, D. Heinert⁶, J. Hough¹, A. Lin³, I. MacLaren¹,
R. Nawrodt⁶, S. Penn⁵, R. Route³, S. Rowan¹

¹ SUPA, University of Glasgow

² SUPA, University of the West of Scotland

³ Stanford University

⁴ American University

⁵ Hobart and William Smith College

⁶ University of Jena

- Introduction

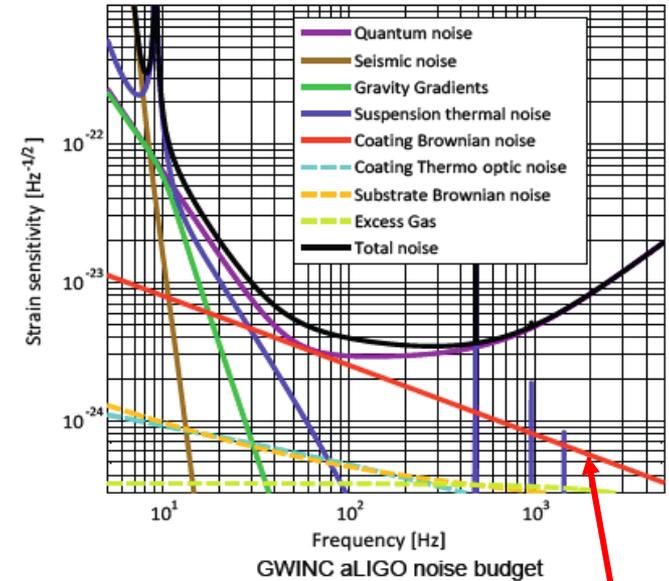
- Measurements of crystalline coatings
 - AlGaAs on silica and silicon
 - AlGaP

- Measurements of amorphous coatings
 - TiO₂ / Ta₂O₅ coatings
 - SiO₂ doped-HfO₂

- Reductions in coating thermal noise required for planned future detectors e.g.

- Enhancements to Advanced LIGO
 - May operate at cryogenic temperature or room temperature (or both – cryo-xylophone)
 - May operate around 1550 nm

- 3rd generation detectors e.g. ET (LF)
 - Cryogenics (10 or 20 K)
 - Change of wavelength to 1550 nm

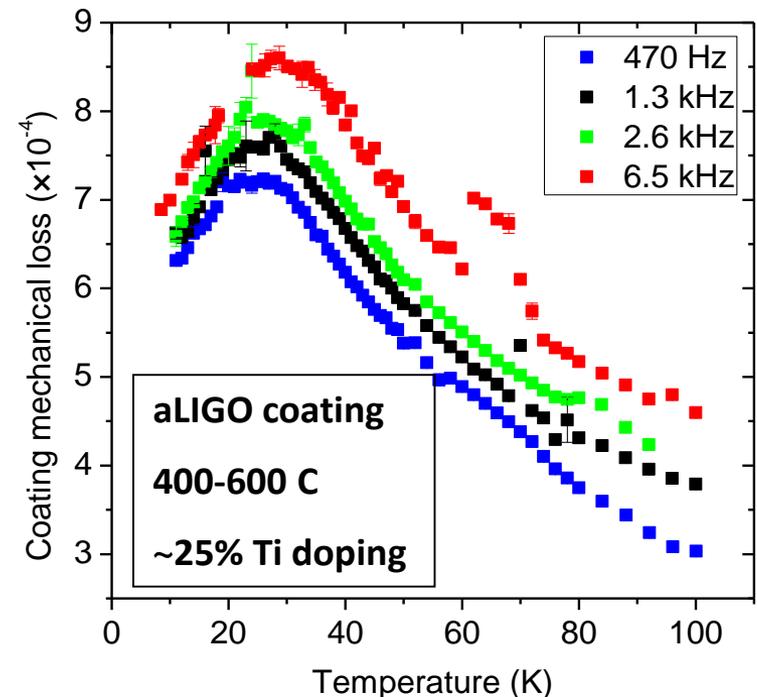
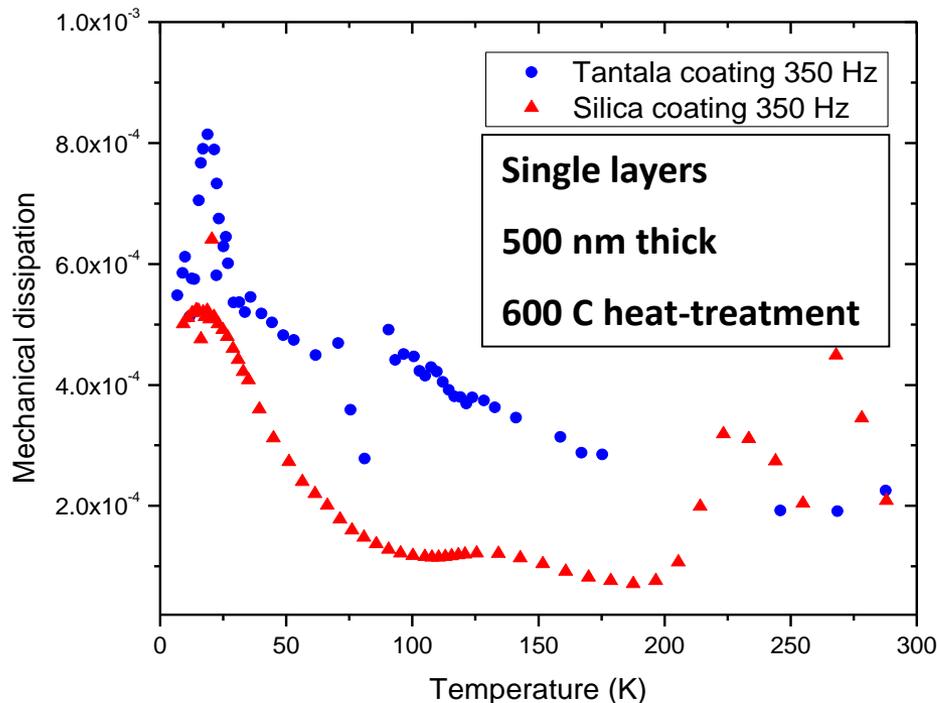


Coating thermal noise

$$S_x(f, T) \approx \frac{2k_B T}{\pi^2 f} \frac{d}{w^2 Y} \phi \left(\frac{Y'}{Y} + \frac{Y}{Y'} \right)$$

Temperature (points to T)
 Coating thickness (points to d)
 Laser beam radius (points to w)
 Coating mechanical loss (points to ϕ)

- Cryogenic loss peaks in tantala / silica films (single layers^{1,2} and aLIGO coating³) suggest reduction in coating thermal noise by $\sim 2x$ by cooling to 20K
 - ET-LF requires loss reduction by $\sim 4x$ (20 K operation) or $\sim 1.6x$ (10 K operation)
 - Peaks at higher temperature (~ 30 K) in multilayer coatings (aLIGO & $\text{SiO}_2/\text{Ta}_2\text{O}_5$ on sapphire measured at ICRR⁴).



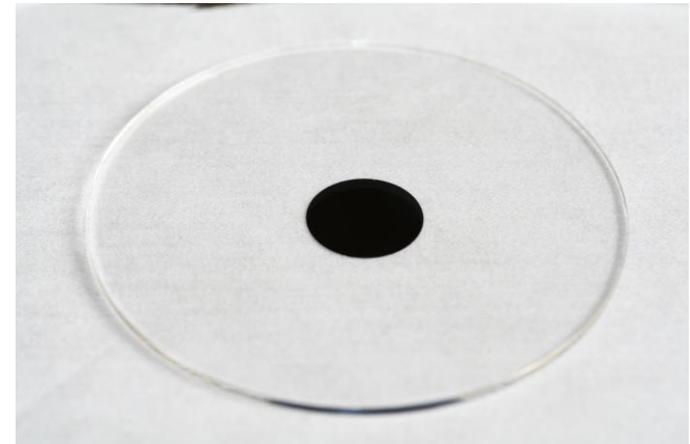
- Improved amorphous coatings:
 - Beginning to understand causes of dissipation
 - Further improvements to current coatings?
 - Alternative materials?

- Crystalline coatings:
 - Intrinsic loss of AlGAs shown to be very low (G. Cole)
 - Measurements of low Brownian noise after being transferred to new substrate.
 - Can they be used successfully on silicon at low temperature?

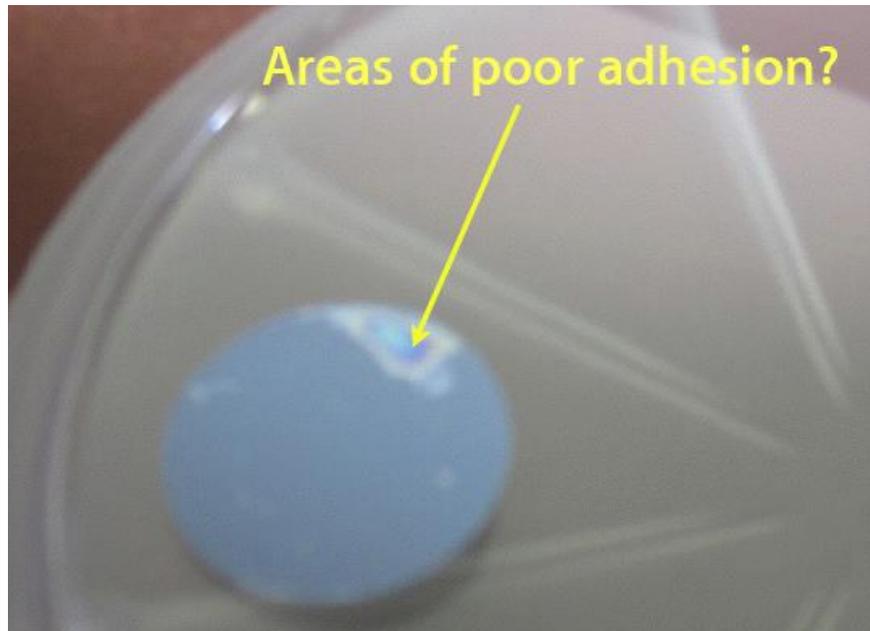
 - GaP/AlGaP alternative - lattice matched to silicon, also very low loss - possible alternative?

- Different solutions may be required for different operating temperatures / wavelengths / mirror substrates – studies ongoing

- AlGaAs micro-resonators - very low mechanical loss ($2.5E-5$ at room temperature, 4.5×10^{-6} at 10 K¹)
- Grown on GaAs, transferred to required mirror substrate
 - Optical cavity measurement – loss of $\sim 4E-5$ at room temperature²
 - Small laser beam will not probe loss of entire bonded coating with equal sensitivity
 - More measurements at frequencies closer to GWD band
- AlGaAs samples
 - 81 alternating layers of GaAs and $Al_{0.92}Ga_{0.08}As$
 - Thickness 6.83 μm , HR at 1064 nm
 - Diameter 16.4 mm
- Bonded to disk substrates by G. Cole
 - SiO₂ substrate – 1.8mm thick x 3" diameter
 - Si substrate – 465 μm thick x 1.54" diameter



- Previous measurements by Steve Penn and Gregg Harry suggested coating loss of $2.1E-4$
- A second sample had visible features between coating and substrate – areas of poor adhesion? Areas changed over time.
- Our sample – appears much better, although some possible defects still visible

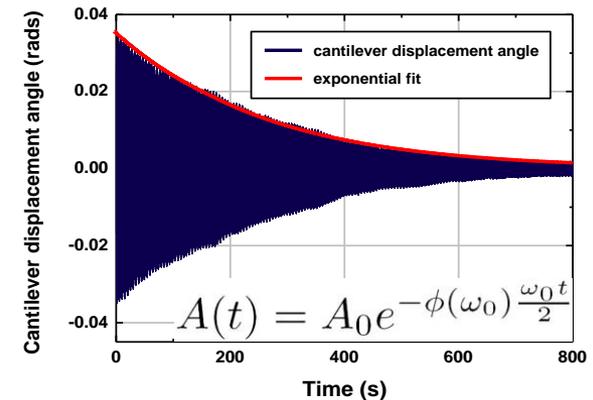
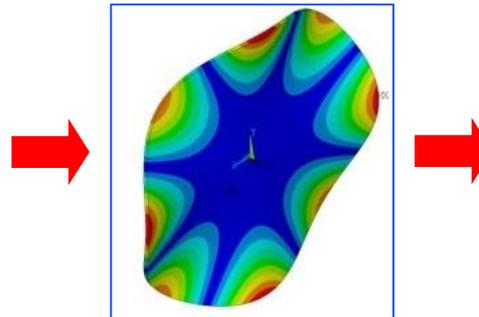
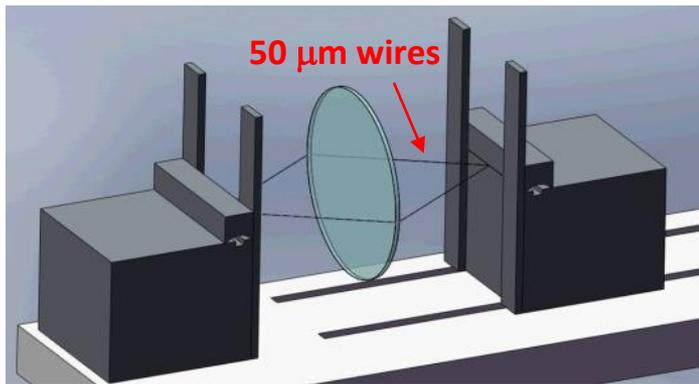


LHS: Samples measured S. Penn and G. Harry

RHS: Our sample, zoomed in to show some features



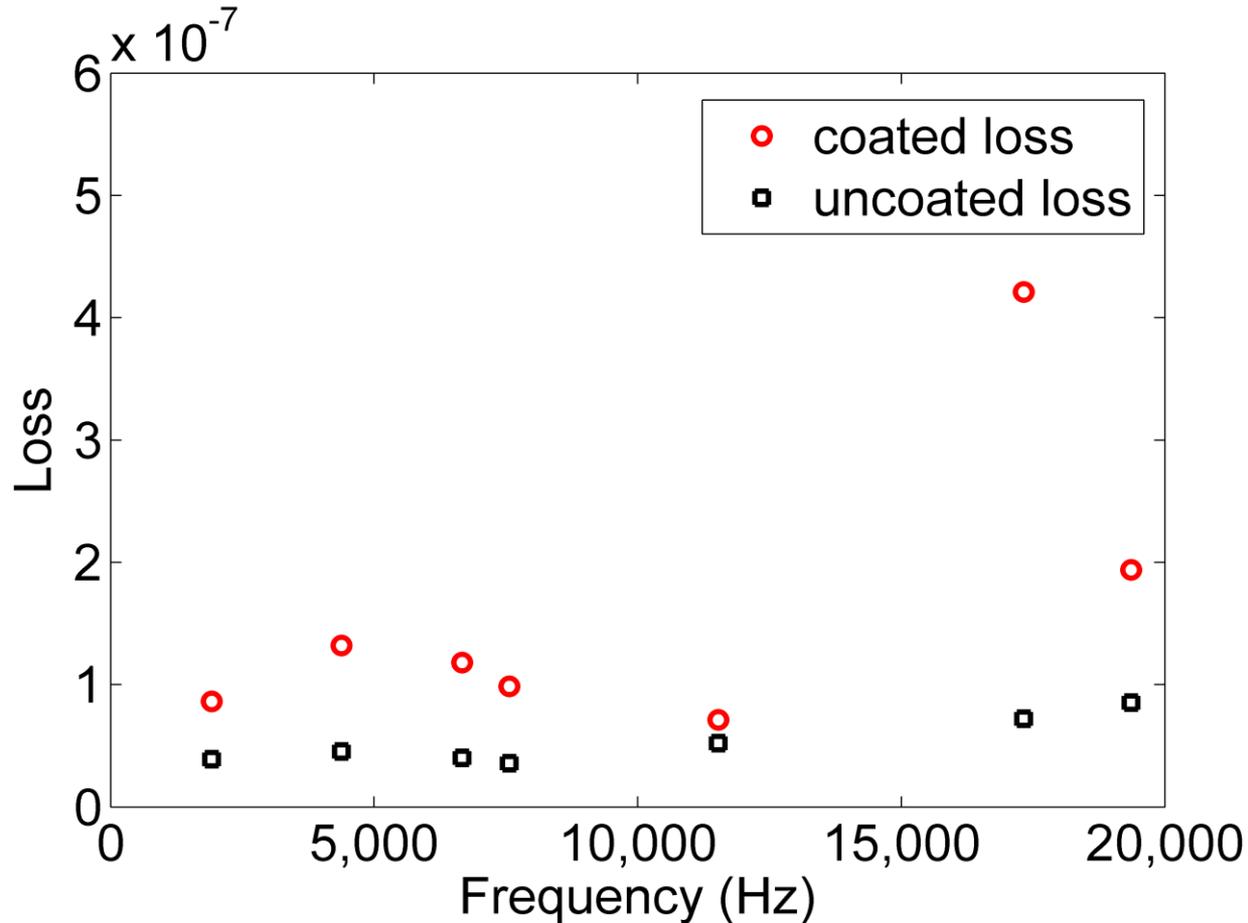
- Disks suspended in a nodal support
- Vibrational modes excited electrostatically, loss from amplitude ring-down



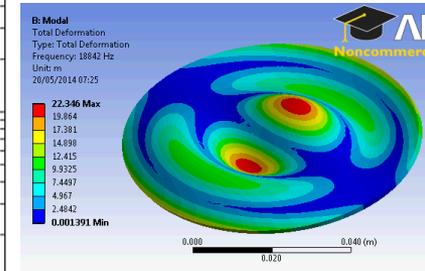
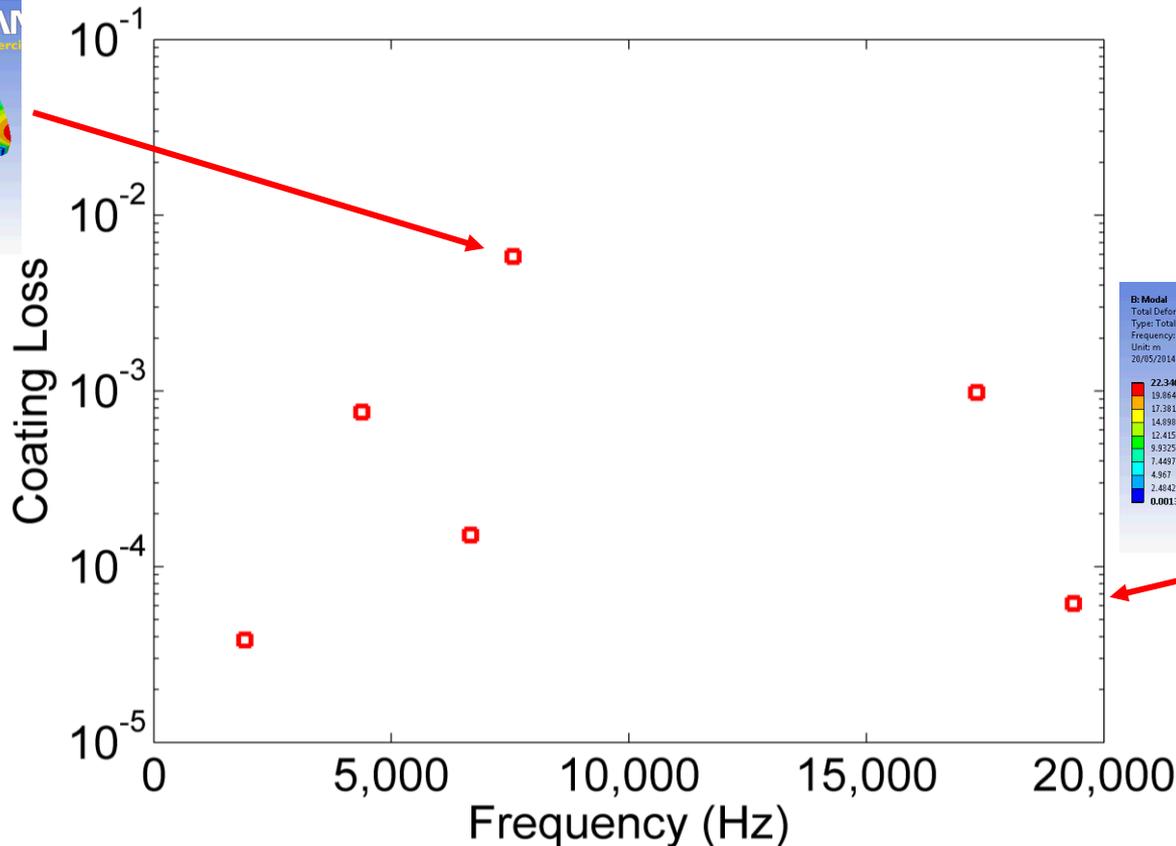
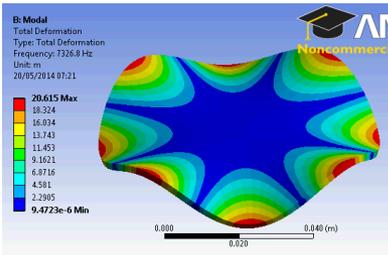
$$\phi_{\text{coating}} = \frac{E_{\text{substrate}}}{E_{\text{coating}}} (\phi_{\text{coated}} - \phi_{\text{un-coated}})$$

- Energy ratio calculated using FE modelling

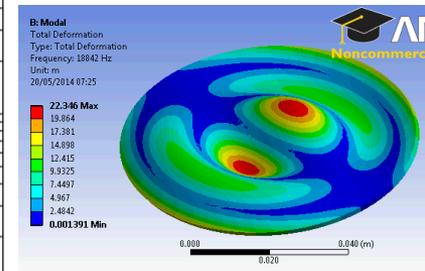
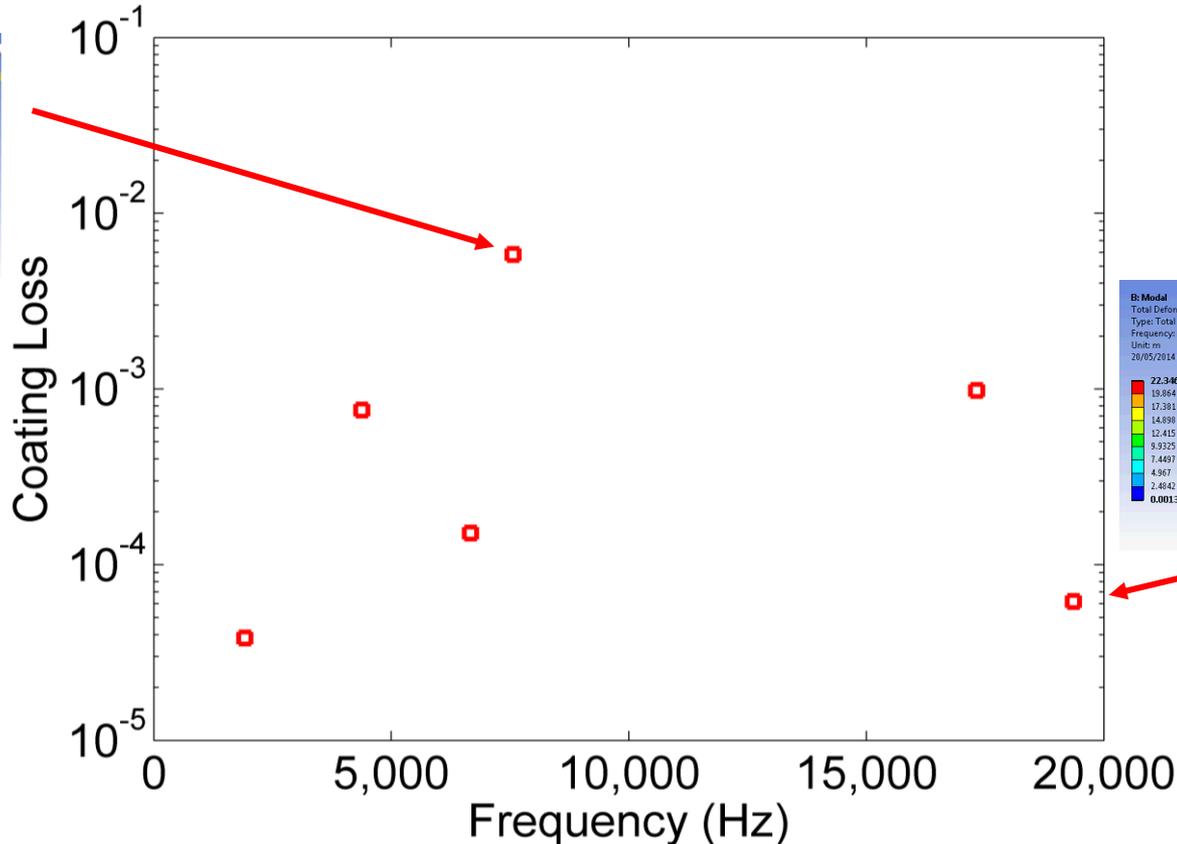
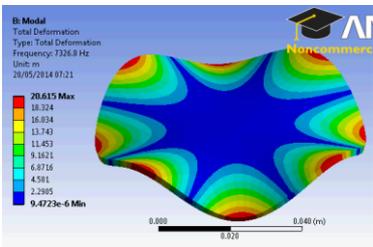
- Room temperature loss measurements of silica disk before and after application of AlGaAs coating



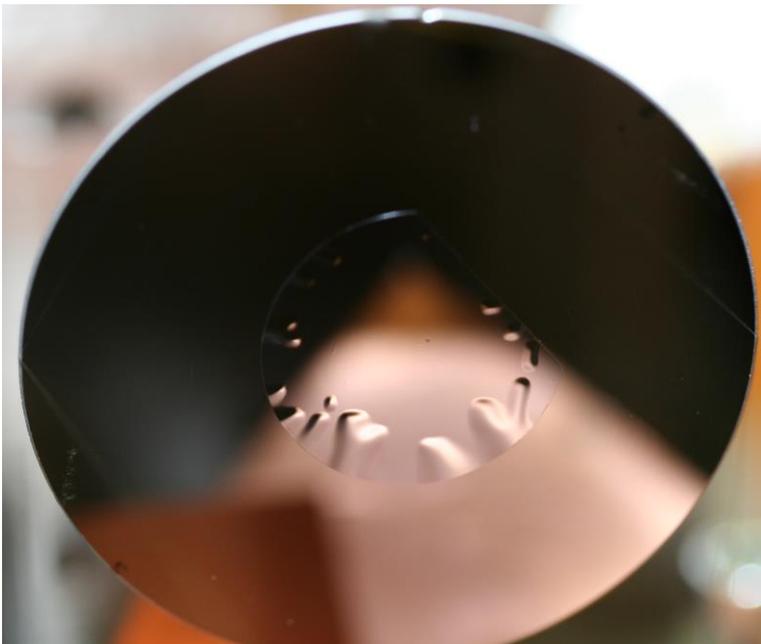
- Calculated coating loss varies significantly for different vibrational modes
- Two modes give losses 3.8E-5 and 6.1E-5 – comparable with (2.5-4)E-5 (Cole 2013)



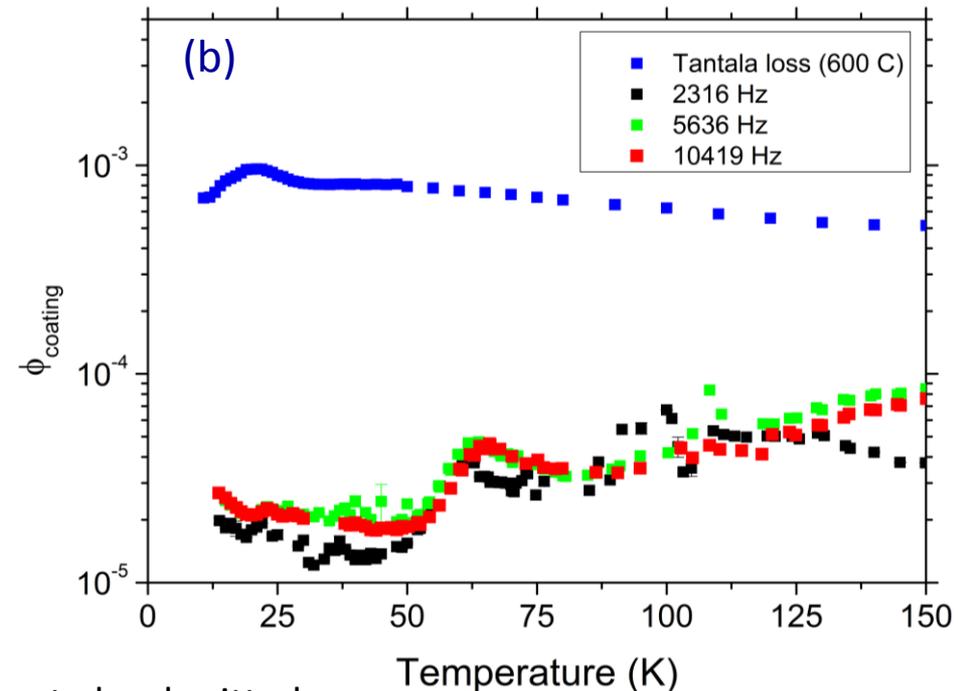
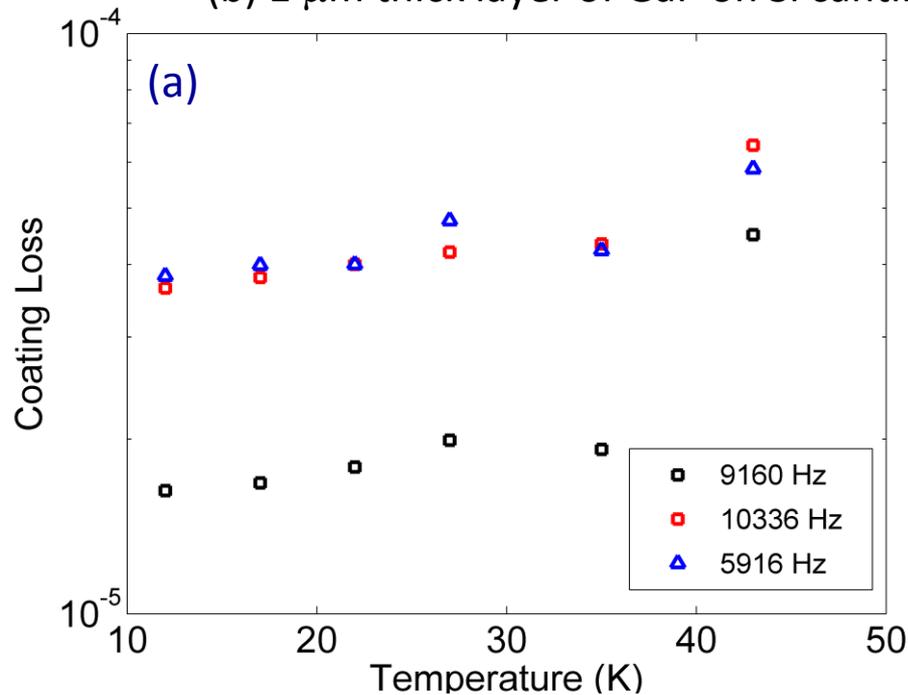
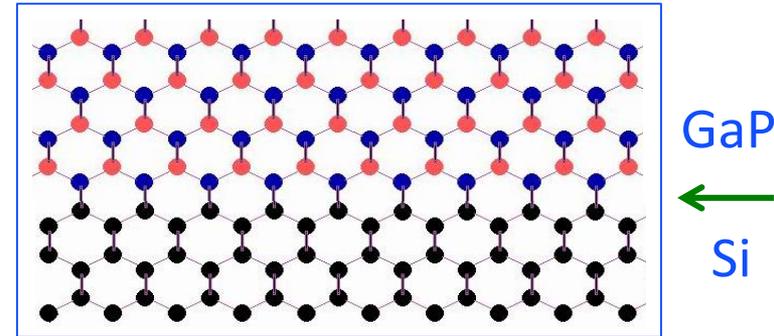
- Why is there so much variation in coating loss?
 - Possible energy loss to suspension wires – re-suspend and repeat
 - Relative energy stored in coating varies significantly with mode shape. Sensitivity to coating loss varies with mode.
 - Coating thermoelastic effects? Further modelling required.



- Delamination observed around edges after 2 cooling cycles to ~14 K (period of ~48 hrs)
 - Garret Cole carried out cooling tests on smaller sample, which survived. Methods of strengthening the bond under investigation



- Alternative crystalline coating system - GaP/AlGaP
- Lattice matched to Si – grown epitaxially on Si substrates (A. Lin et al, Stanford)
- Measurements of
 - (a) 10 GaP/AlGaP bi-layer stack on Si disk¹
 - (b) 1 μm thick layer of GaP on Si cantilever

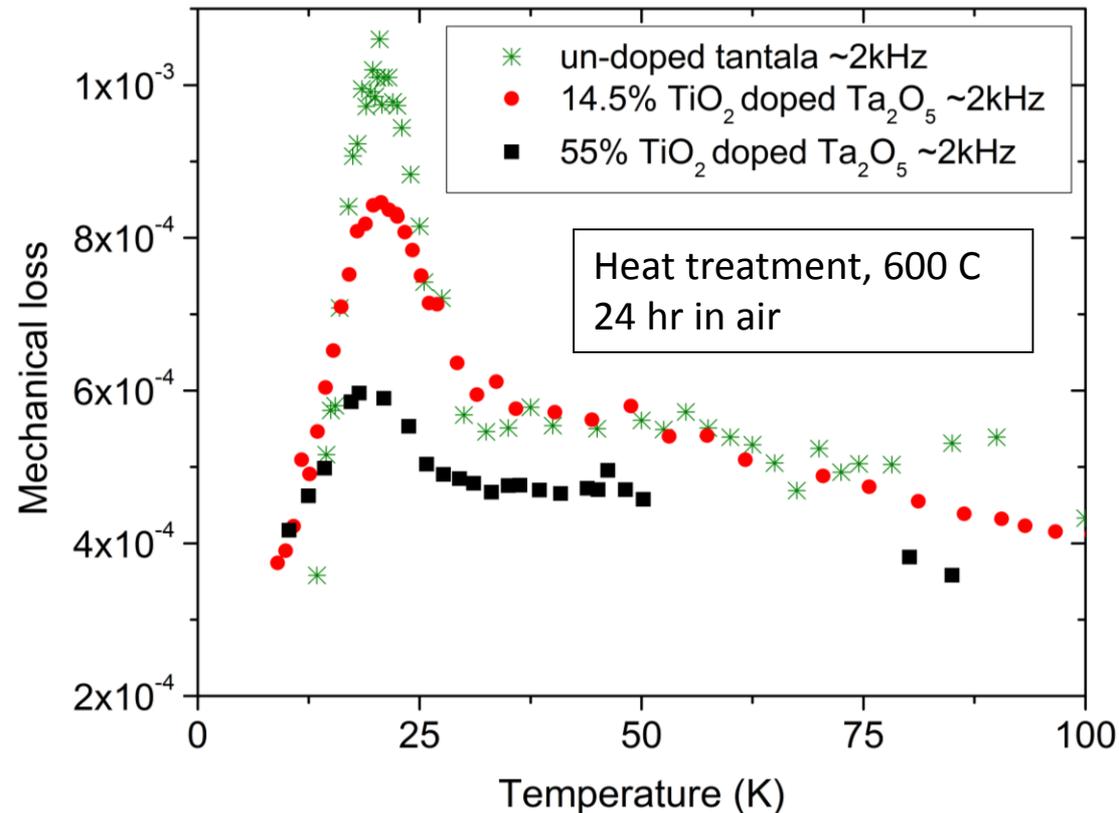


¹A. Cumming et al, submitted

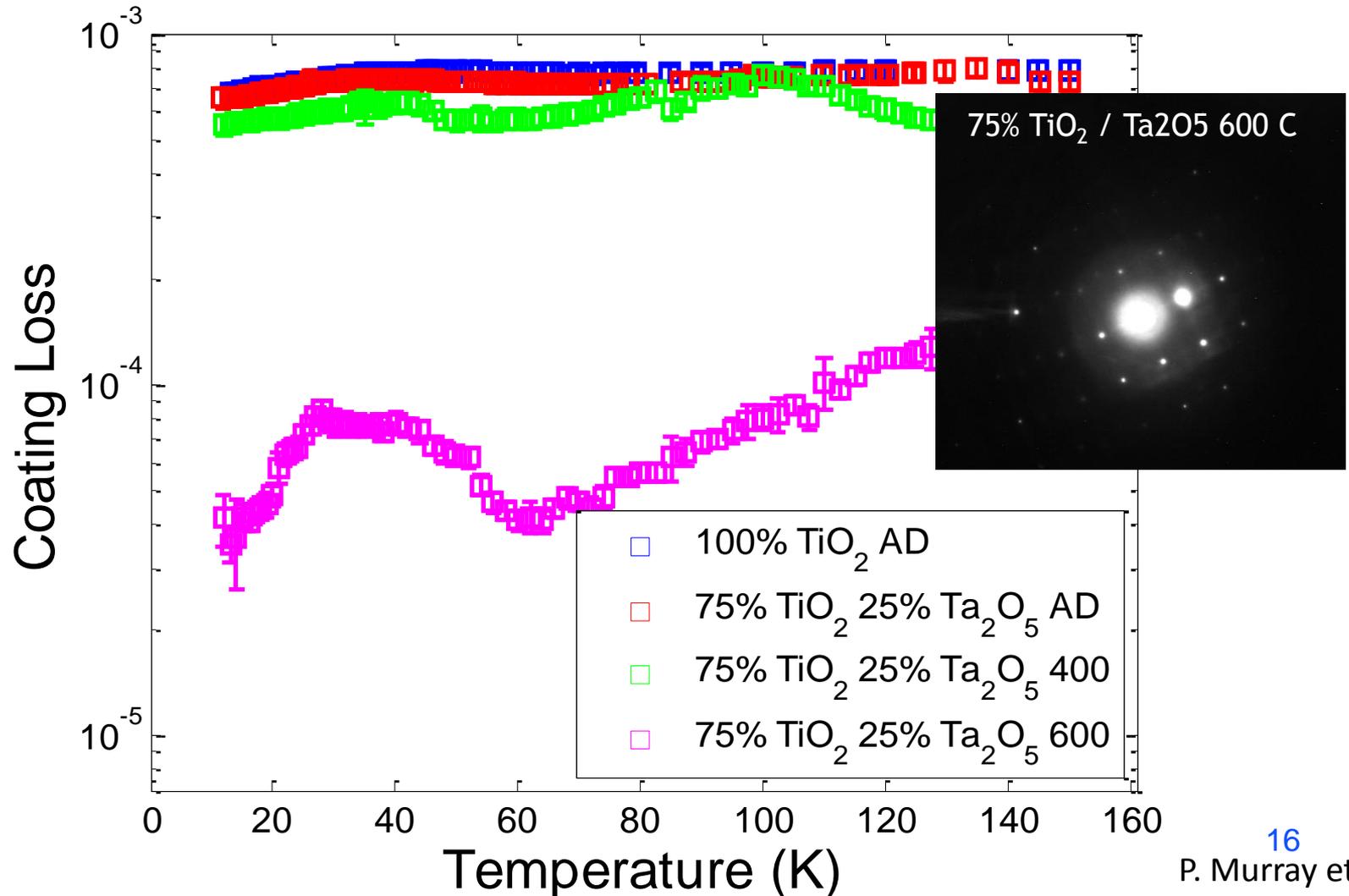
- AlGaAs
 - On silica, 290 K – lowest coating loss $3.6E-5$
 - On silicon – coating detaching after two temperature cycles

- AlGaP
 - First coating, loss $< \sim 4E-5$ below 40 K
 - Consistent with upper limit for single layer GaP

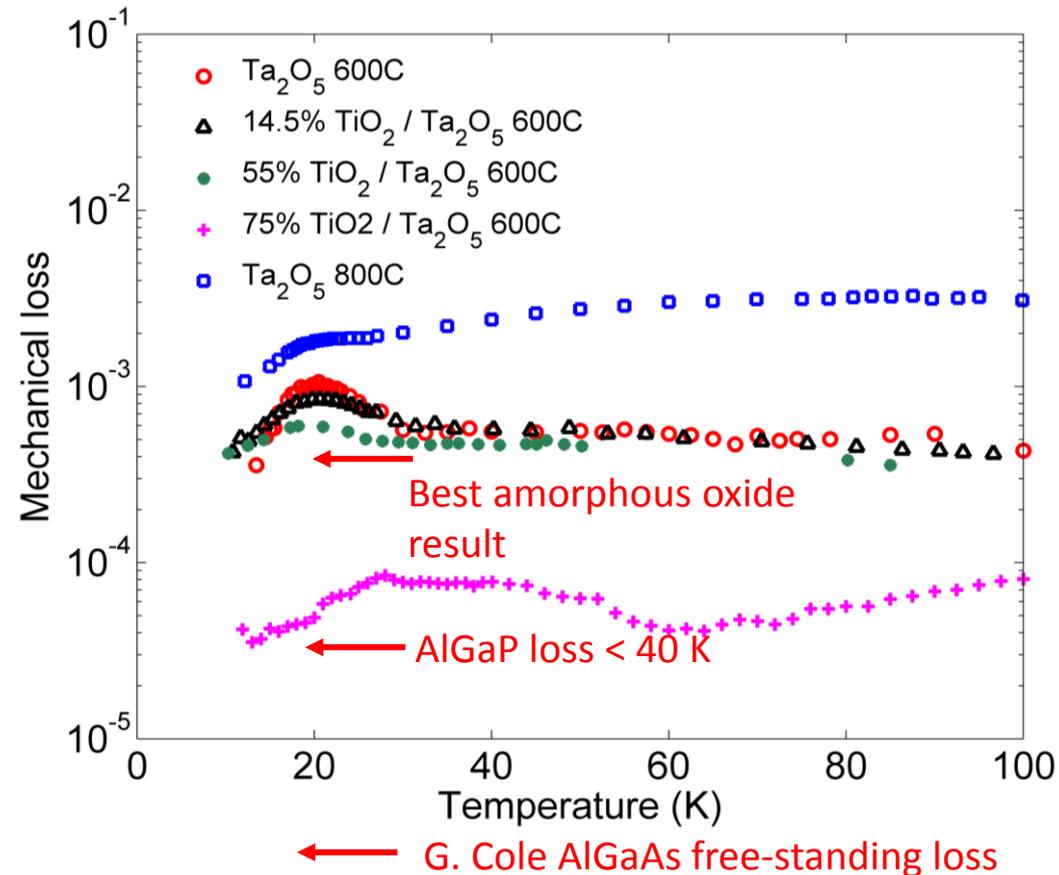
- Increased TiO_2 doping reduces the cryogenic loss, particularly with heat-treatment
 - Insight into loss mechanisms, parallel structural measurements (R. Bassiri talk)
- New studies of:
 - pure TiO_2
 - Interest for nano-layer coatings (Shiuh Chao, Innocenzo Pinto)
 - $Y_{\text{TiO}_2} = 141 \text{ GPa}$ (Shiuh Chao, IBS TiO_2)
 - 75% TiO_2 / 25% Ta_2O_5
 - Further improvement in loss?
 - 0.5 μm thick films, $\sim 60 \mu\text{m}$ thick Si cantilever substrates



- Cryogenic loss of as-deposited TiO₂ and 75% TiO₂ / 25 % after various heat treatments

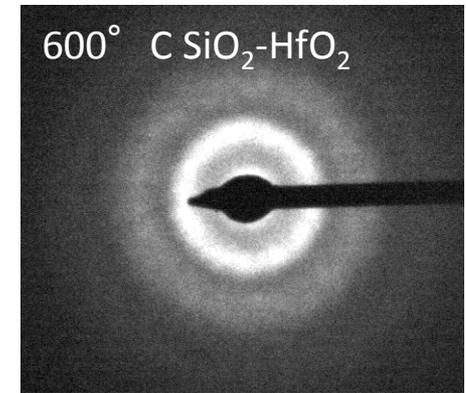
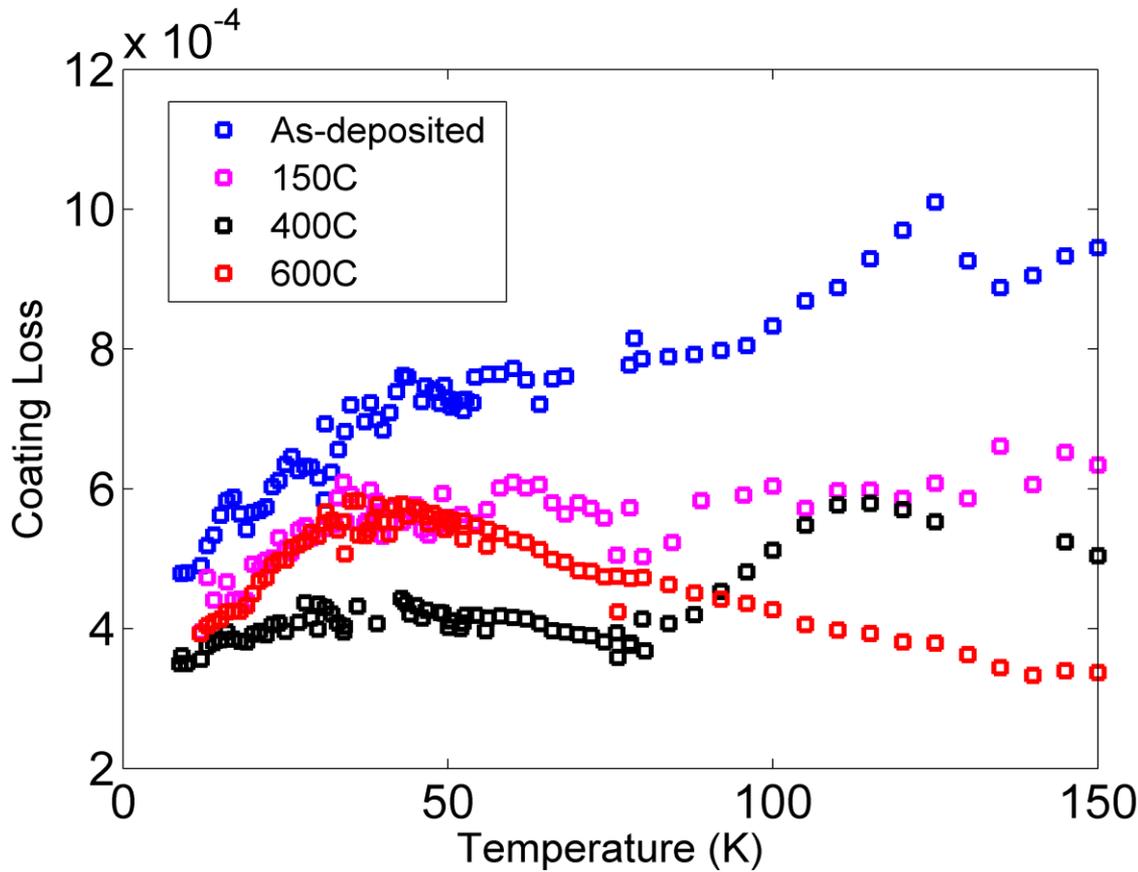


- 75% TiO₂ (600C) coating has **anomalously low loss**
- Crystallized pure Ta₂O₅ displayed large 90 K loss peak
- 75% coating - crystallized more fully?
- Absorption / scatter measurements of interest



- Titania doping can suppress cryogenic loss peak in tantalum
- 75% TiO₂/Ta₂O₅
 - 400C heat treatment reduces cryogenic loss
 - crystallises at 600C, anomalously low cryogenic loss

- 30% silica-doped hafnia (CSIRO, 500 nm, Si cantilevers)
 - Silica prevents crystallisation, heat-treatment up to 400 C reduces loss
 - Best amorphous oxide coating so far, (almost) no low temperature loss peak



- Silica-doped hafnia (400C) close to meeting ET-LF (10K) loss requirements
- As Innocenzo suggested, SiO_2 -doped TiO_2 may be of interest (good room temperature loss, prevent crystallization)

- Crystalline coatings
 - AlGaAs on SiO₂ - loss 3.6×10^{-5} @ 290 K
 - AlGaAs on Si – partially detached during cryogenic cycling
 - work required to produce stronger bond
 - Prototype GaP/AlGaP MBE coating on Si is $<4 \times 10^{-5}$ below 40 K

- Amorphous coatings
 - Anomalously low loss for crystallized 75%TiO₂/Ta₂O₅ (600C)
 - SiO₂-doped HfO₂ (400C) best amorphous oxide so far, no low T peak
 - SiO₂ doping in TiO₂ of interest

- Coating thermoelastic loss (Fejer et al, 2004)
 - Maximum TE loss is shown in the plot
 - Calculate fraction of energy γ associated with volume change for each mode

$$\phi_{\text{coating}} = \phi_{\text{intrinsic}} + \gamma\phi_{\text{coatingTE}}$$

- $\phi_{\text{coatingTE}}$ using AlGaAs properties from Cole 2013
- Coating TE loss likely has significant contribution to coating loss
- Further FE modelling required

